

ECE 3030: Physical Foundations of Computer Engineering

Fall 2021

Homework 3—Total points 100

Due on Thursday 9/23/2020 at 11.59 am.

- Q1 Have you downloaded the textbook: Modern Semiconductor Devices for Integrated Circuits by Chenming Calvin Hu? Write down the web address of the textbook where one can freely download it from. [20 pts]

Solution to Q1: Yes, I have downloaded the text book from this address:

<https://people.eecs.berkeley.edu/~hu/Book-Chapters-and-Lecture-Slides-download.html>

- Q2 Draw the band diagram (the relative positions of conduction band edge E_C , valence band edge E_v , Fermi level E_F) for the four following cases. Clearly note $E_C - E_F$, $E_F - E_V$, $E_i - E_F$, $E_G = E_C - E_V$. E_i is the intrinsic Fermi level. Take $N_C=N_V=10^{25} \text{ m}^{-3}$, $E_G=1.1 \text{ eV}$, $n_i=1.5 \times 10^{16} \text{ m}^{-3}$, $kT=0.026 \text{ eV}$. [60 pts]

(Q1.1) p-type, $N_A=5 \times 10^{23} \text{ m}^{-3}$.

(Q1.2) p-type, $N_A=5 \times 10^{21} \text{ m}^{-3}$.

(Q1.3) n-type, $N_D=5 \times 10^{23} \text{ m}^{-3}$.

(Q1.4) n-type, $N_D=5 \times 10^{21} \text{ m}^{-3}$.

Solution to Q2: Solution in the next two pages.

5.

$$E_G = 1.1 \text{ eV}, N_C = N_V = 10^{25} \text{ m}^{-3}$$

$$n_i = 1.5 \times 10^6 \text{ m}^{-3}, kT = 0.026 \text{ eV}$$

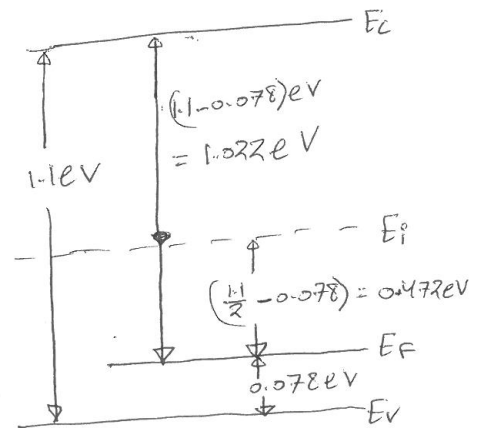
(5.1) p type, $N_A = 5 \times 10^{23} \text{ m}^{-3}$

$$p = N_A = N_V e^{\frac{E_V - E_F}{kT}}$$

$$\Rightarrow E_V - E_F = kT \ln \frac{N_A}{N_V}$$

$$= 0.026 \ln \frac{5 \times 10^{23}}{10^{25}}$$

$$= -0.078 \text{ eV}$$



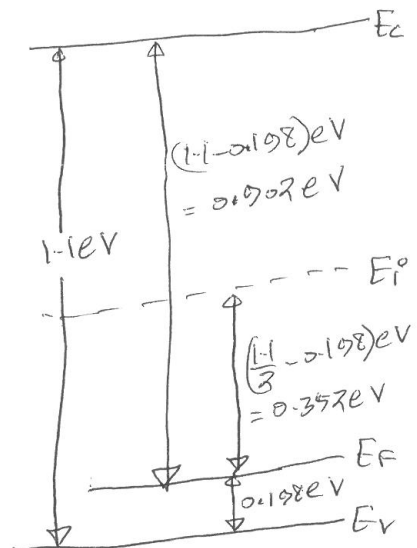
(5.2) p type, $N_A = 5 \times 10^{21} \text{ m}^{-3}$

$$p = N_A = N_V e^{\frac{E_V - E_F}{kT}}$$

$$\Rightarrow E_V - E_F = kT \ln \frac{N_A}{N_V}$$

$$= 0.026 \ln \frac{5 \times 10^{21}}{10^{25}}$$

$$= -0.198 \text{ eV}$$



5.3

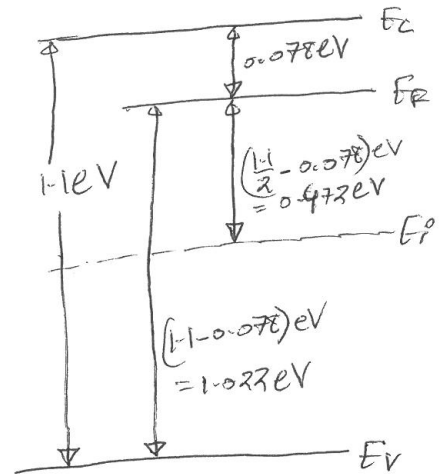
n type, $N_D = 5 \times 10^{23} \text{ m}^{-3}$

$$n = N_D = N_C e^{\frac{E_F - E_C}{k_B T}}$$

$$\Rightarrow E_F - E_C = k_B T \ln\left(\frac{N_D}{N_C}\right)$$

$$= 0.026 \ln\left(\frac{5 \times 10^{23}}{10^{25}}\right)$$

$$= -0.078 \text{ eV}$$



5.4

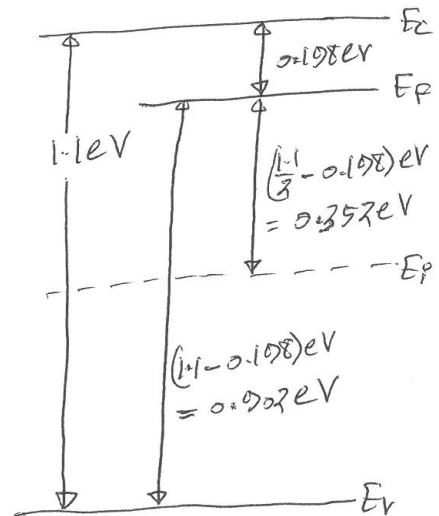
n type, $N_D = 5 \times 10^{21} \text{ m}^{-3}$

$$n = N_D = N_C e^{\frac{E_F - E_C}{k_B T}}$$

$$\Rightarrow E_F - E_C = k_B T \ln\left(\frac{N_D}{N_C}\right)$$

$$= 0.026 \ln\left(\frac{5 \times 10^{21}}{10^{25}}\right)$$

$$= -0.108 \text{ eV}$$



Q3 Explain in short why at absolute zero temperature silicon will not conduct any electric current. [20 pts]

Solution to Q3: Absolute temperature (0K) means there is no thermal energy. At this temperature, the valence electrons of Si are bound to its nucleus. Hence, when we apply a voltage across Si, there is no free electron, which means there is no current flowing through Si.